

Paragraph beginning at page 13, line 26 has been amended as follows:

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The invention may include any inventive feature or combination of features disclosed herein either implicitly or explicitly or any generalisation thereof, without limitation to the scope of any of the present claims. In view of the foregoing description it will be evident to a person skilled in the art that various modifications may be made within the scope of the invention.

IN THE ABSTRACT:

Please add an abstract as set forth on the attached sheet.

IN THE CLAIMS:

Please amend claims 4, 5, 7-19, and 22 as follows:

4. (Amended) An opto-electrical device as claimed in claim 1, wherein the compound is a fluoride.

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5. (Amended) An opto-electrical device as claimed in claim 2, wherein the metal is a group 1 or 2 metal.

7. (Amended) An opto-electrical device as claimed in claim 2, wherein the said one of the layers is the first layer.

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8. (Amended) An opto-electrical device as claimed in claim 2, wherein the said one of the layers is the second layer.

9. (Amended) An opto-electrical device as claimed in claim 2, wherein the other of the first and second layers comprises a metal.

10. (Amended) An opto-electrical device as claimed in claim 9, wherein the other of the first and second layers comprises a metal selected from the group consisting of Li, Ba, Mg, Ca, Ce, Cs, Eu, Rb, K, Y, Sm, Na, Sm, Sr, Tb and Yb.

11. (Amended) An opto-electrical device as claimed in claim 1, wherein the second layer is thicker than the first layer.

12. (Amended) An opto-electrical device as claimed in claim 1, wherein the thickness of the second layer is greater than 100 Å.

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13. (Amended) An opto-electrical device as claimed in claim 1, wherein the said material having a work function below 3.5 eV of which the first layer is comprised has a higher work function than the said material having a work function below 3.5 eV of which the second layer is comprised.

14. (Amended) An opto-electrical device as claimed in claim 1, wherein the thickness of the third layer is greater than 1000 Å.

15. (Amended) An opto-electrical device as claimed in claim 1, wherein the said material having a work function above 3.5 eV has an electrical conductivity greater than $10^5 (\Omega \cdot \text{cm})^{-1}$.

16. (Amended) An opto-electrical device as claimed in claim 1, wherein the said material having a work function above 3.5 eV is aluminium, gold or indium-tin oxide.

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17. (Amended) An opto-electrical device as claimed in claim 1, wherein the cathode is transparent.

18. (Amended) An opto-electrical device as claimed in claim 1, wherein the opto-electrically active region is light-emissive.

19. (Amended) An opto-electrical device as claimed in claim 1, wherein the opto-electrically active region comprises a light-emissive organic material.

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22. (Amended) An opto-electrical device as claimed in claim 19, comprising a charge transport layer between the light-emissive organic material and one of the electrodes.

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Please delete claims 24 and 25, without prejudice.

✓
Please add new claims 26-31, as follows:

26. An opto-electrical device as claimed in claim 4, wherein the metal is a group 1 or 2 metal.

27. An opto-electrical device as claimed in claim 26, wherein the metal is lithium.

28. An opto-electrical device as claimed in claim 4, wherein the said one of the layers is the first layer.

29. An opto-electrical device as claimed in claim 4, wherein the said one of the layers is the second layer.

30. An opto-electrical device as claimed in claim 4, wherein the other of the first and second layers comprises a metal.

31. An opto-electrical device as claimed in claim 30, wherein the other of the first and second layers comprises a metal selected from the group consisting of Li, Ba, Mg, Ca, Ce, Cs, Eu, Rb, K, Y, Sm, Na, Sm, Sr, Tb and Yb.

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